

Innovative DC-coupled Resistive Silicon Detectors for 4D tracking

R. Arcidiacono (Università del Piemonte Orientale & INFN Torino)

on behalf of the 4DSHARE project

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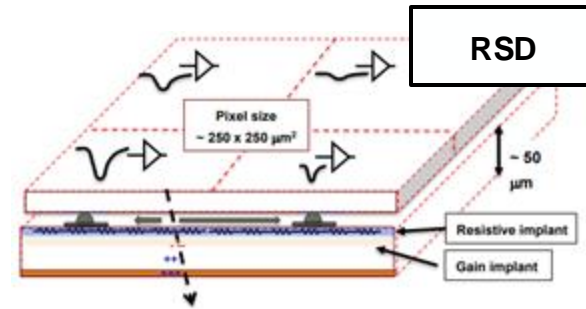
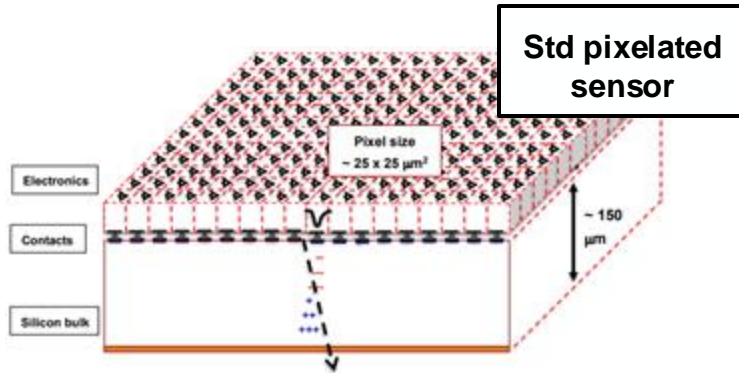
M. Centis Vignali, M. Boscardin, O. Hammad Ali, G. Paternoster (FBK)

A. Morozzi, T. Croci, A. Fondacci, F. Moscatelli, D. Passeri (Univ. & INFN Perugia, CNR)

L. Viliani, M. Bartolini, G. Bardelli, A. Cassese, M. Lizzo, G. Sguazzoni (INFN Firenze)

17th Vienna Conference on Instrumentation 17-21 Feb. 2025

The paradigm for silicon trackers using “resistive LGAD”



- **Binary read-out:** $\sigma_{\text{Pixel}} \sim 0.3 \cdot \text{pitch}$
- **resistive LGADs:** $\sigma \sim 0.03\text{-}0.05 \cdot \text{pitch}$
- **resistive LGADs** time resolution with thin detectors → **30-40 ps** for **50 micron thick**

similar space resolution with reduced number of read-out channels (a factor of ~100 less)
 smaller material budget
 excellent time resolution

Space resolution with RSDs

AC-coupled resistive LGADs → RSD

FBK RSD2 (2021) best design: Swiss cross electrodes.

Position performance have been explored with laser and at several test beams.

Results with electron testbeam (DESY)

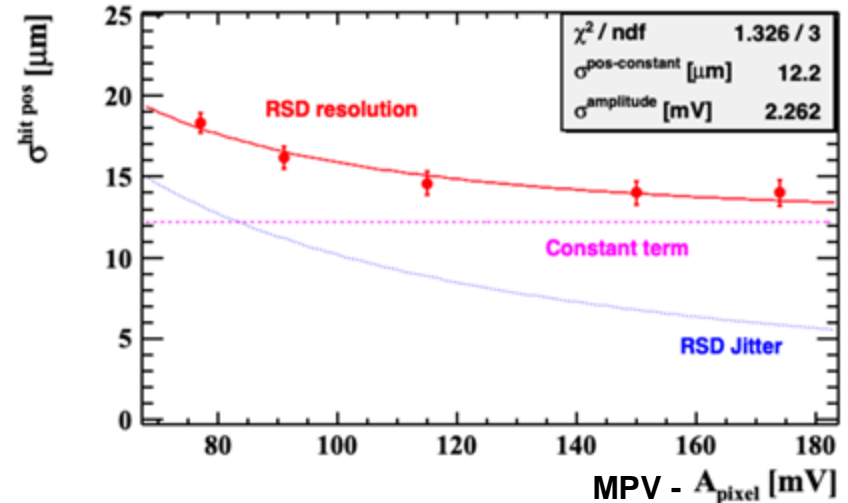
RSD2-450, pixel 450 x 450 μm^2 - 16 electrodes read out
16ch FAST2 Board (INFN Torino) + CAEN Digitizer

The constant term dominates the resolution $\sigma_{\text{constant}} \sim 13 \mu\text{m}$
It includes mis-alignment RSD-Tracker, sensor and electronics
non uniformity, etc...

Resolution around **3%-4% of the pitch.**

L. Menzio et al, "First test beam measurement of the 4D resolution of an RSD 450 microns pitch pixel matrix connected to a FAST2 ASIC", JNIMA 1065 (2024), 169526

RSD2-450-micron pitch

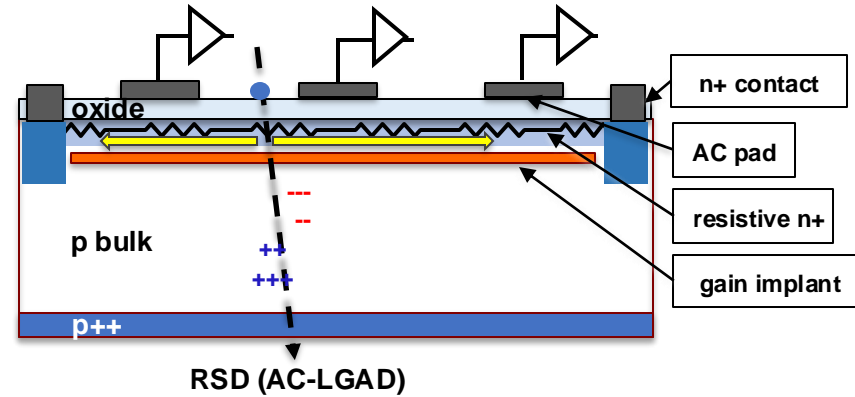


$$\sigma^{\text{hit pos}} = \sqrt{(\sigma^{\text{pos-constant}})^2 + \left(\frac{\sigma^{\text{amplitude}} \times \text{pitch}}{\sum_i^4 A_i}\right)^2}$$

Next evolution: DC-coupled RSD

RSD sensors show some non-ideal features:

- Signal **spread** may involve a large (>4) and **variable number of electrodes**, leading to slight deterioration and a non-uniform **spatial resolution over the sensor surface**
- **Baseline fluctuations** (leakage current collection only at the edge) in large and/or irradiated devices
- **Signals are bipolar** with rather long tails during the discharge



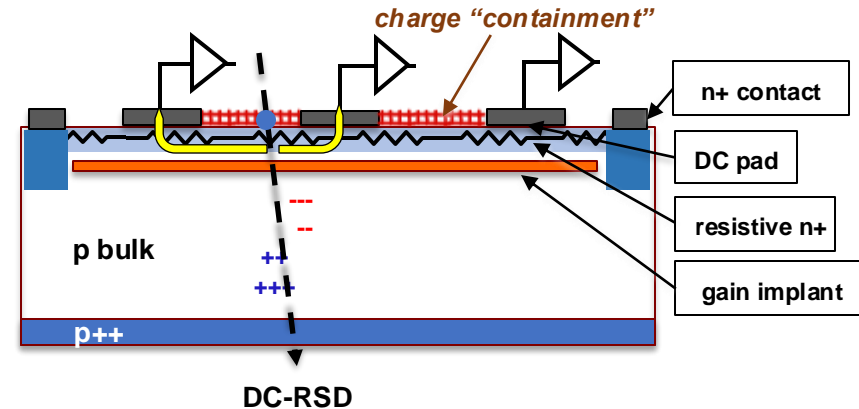
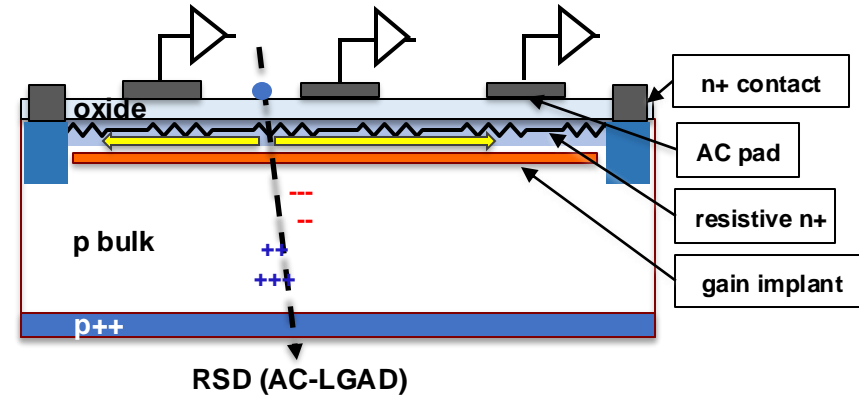
DC-coupled Resistive Silicon Detectors

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Evolution of the RSD design:

DC collection of signals, with low resistivity paths to readout pads + charge “containment” structures (isolating trenches for now) ⇒ **DC-RSD design**

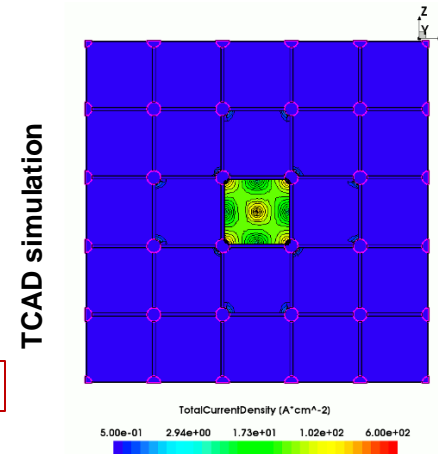
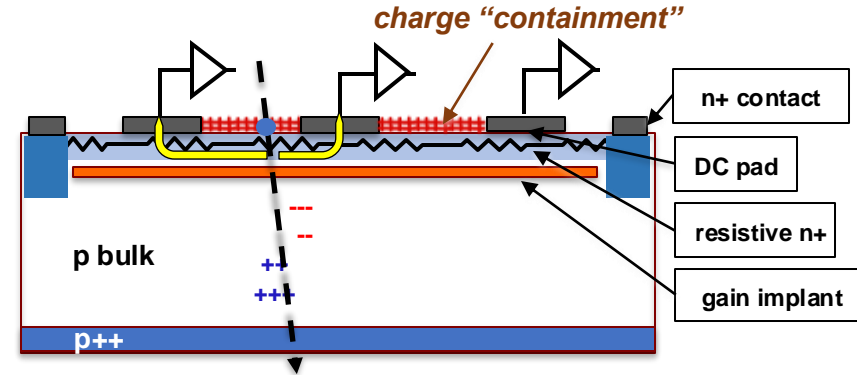


DC-coupled Resistive Silicon Detectors

In the DC-RSD design

- Signal is confined: **charge sharing in a predetermined number of pads**
 - the leakage currents is removed locally at each electrodes
 - No bipolar signal → 1-2 ns-long pulses
- **expected more uniform performance and design scalable to large devices**

Extensive simulation studies performed to optimize design: resistive path, charge sharing, electrodes geometry, confinement method...



DC-RSD with trenches
current density over device surface, generated by a hit in the center of the pixel → **expected signal confinement**

F. Moscatelli et al, <https://www.sciencedirect.com/science/article/pii/S0168900224003061>

A. Fondacci's talk at Pixel2024

DC-RSD1: “proof-of-concept” production

DC-RSD developments: supported by 3 national **Grants** [4DinSiDe, 4DSHARE projects] so far.

The first production **was completed @FBK in November 24: DC-RSD1**

- The solution selected to achieve **charge containment:** use of **Isolating Trenches** (like TI-LGADs or SiPM)

DC-RSD1: “proof-of-concept” production

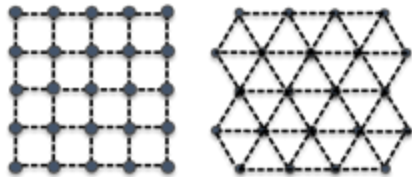
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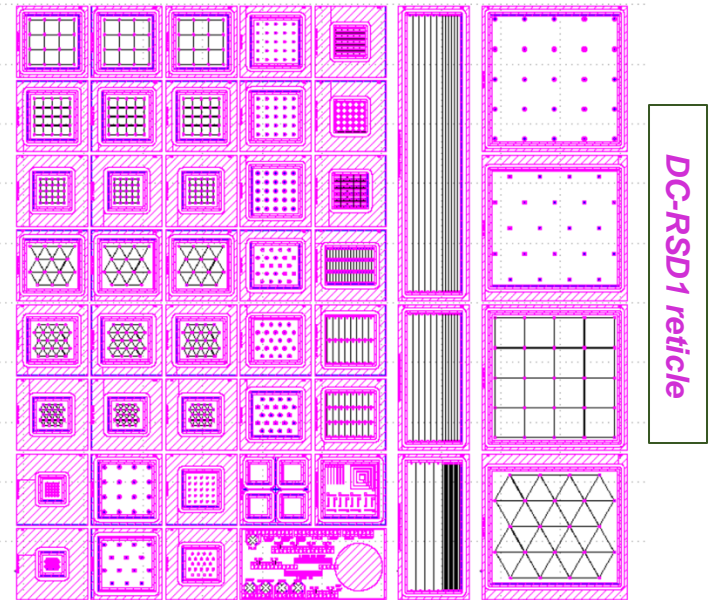
Several test structures implemented:

- devices with **squared** or **hexagonal matrix of electrodes** (dot-shaped), **with and without isolating trenches**, multiple pitch options
- strips with multiple pitch options and multiple length**



“square” or “triangle” pixel shape

- devices without isolating trenches have been implemented to allow comparison with the equivalent designs in AC-LGADs



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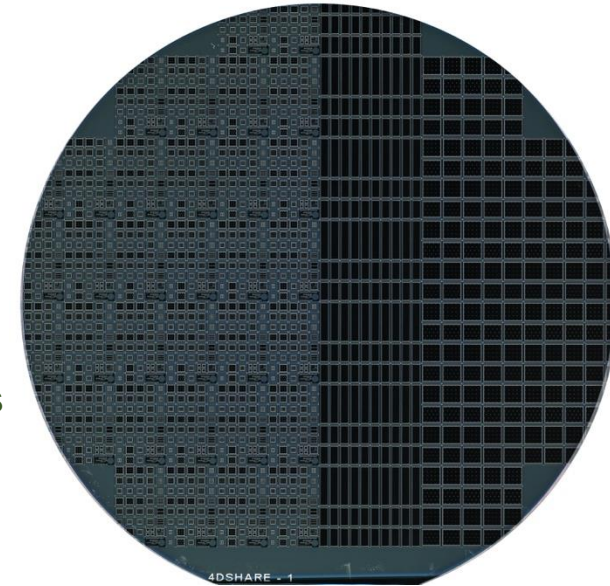
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Split table:

Wafer	NPLUS dose	CONHO IMP	Trench depth	Trench process	PGAIN dose	Thickness
1	0,25		D2	P2	1.02	55
2	0,25	Y	D2	P2	1.02	55
3	0,25	Y	D2	P2	1.06	55
4	0,25	Y	D2	P2	1.06	55
5	0,5		D2	P2	1.02	55
6	0,5		D2	P2	1.06	55
7	0,5	Y	D2	P2	1.06	55
8	0,5	Y	D2	P2	1.02	55
9	1		D2	P2	1.02	55
10	1		D2	P2	1.06	55
11	1	Y	D2	P2	1.02	55
12	1	Y	D2	P2	1.06	55
13	0,25	Y	D2	P2	1.06	55
14	0,5	Y	D2	P2	1.02	55
15	1	Y	D2	P2	1.06	55

wafer selected
for lab and
testbeam
measurements



DC-RSD1 wafer

see M. Centis Vignali's Talk at TREDI2025 for more information on the DC-RSD1 production

DUTs @DESY testbeam

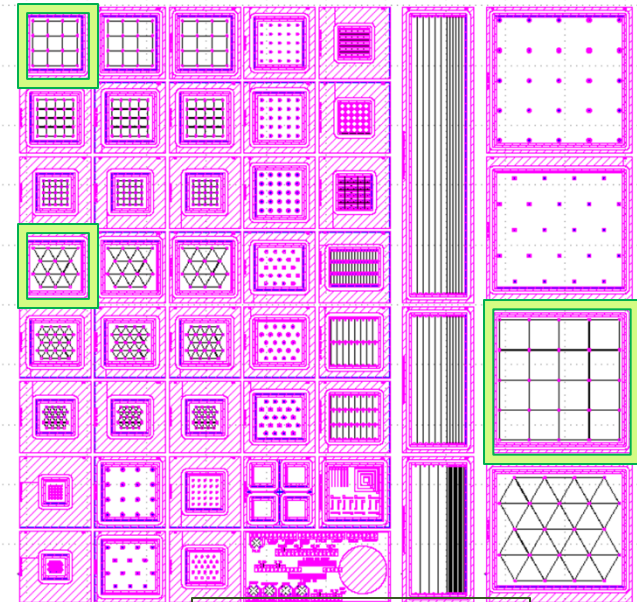
Today: preliminary results on space and time resolutions of these devices measured with a 5 GeV electron beam (DESY)

“Square” pixels

- 3x3 pixel matrix
- 16 electrods
- 500- and 1000-micron pitch

“Triangle” pixels

- 5x3 pixel matrix
- 14 electrodes
- 500-micron pitch



DC-RSD1 reticle

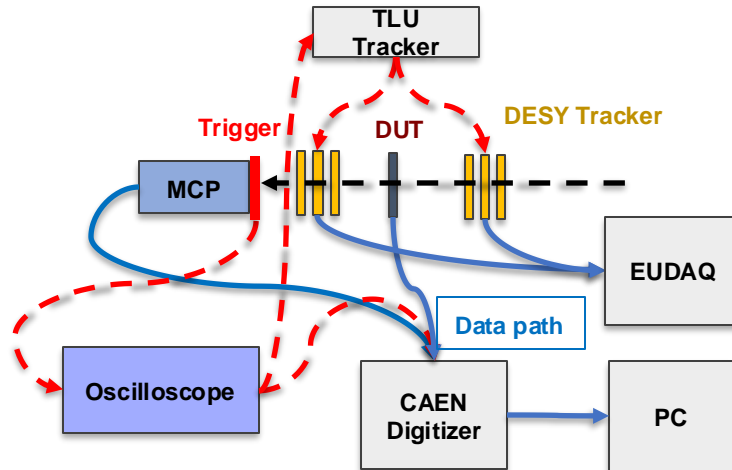
The DESY test beam set-up

Two different data taking modes

Studies of spatial resolution

Read many pixels using a CAEN digitizer

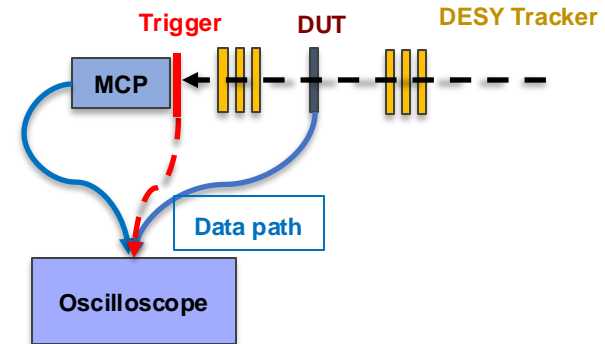
- Up to 16 electrodes



Studies of time resolution

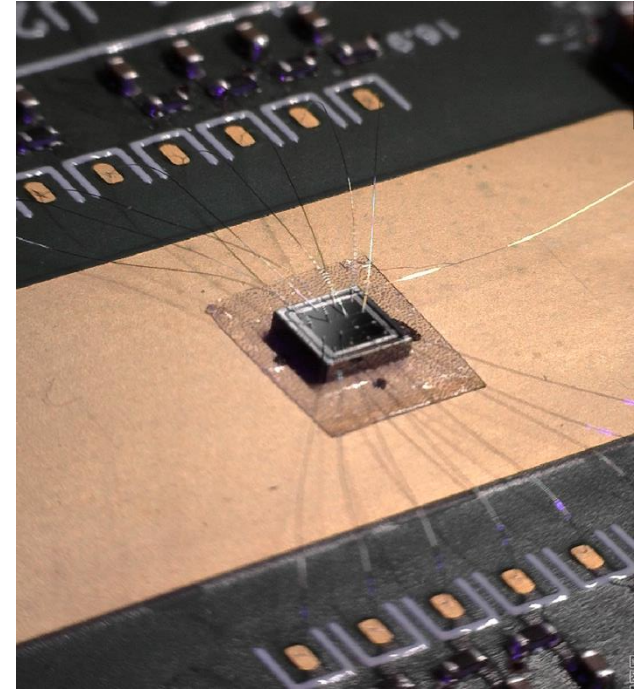
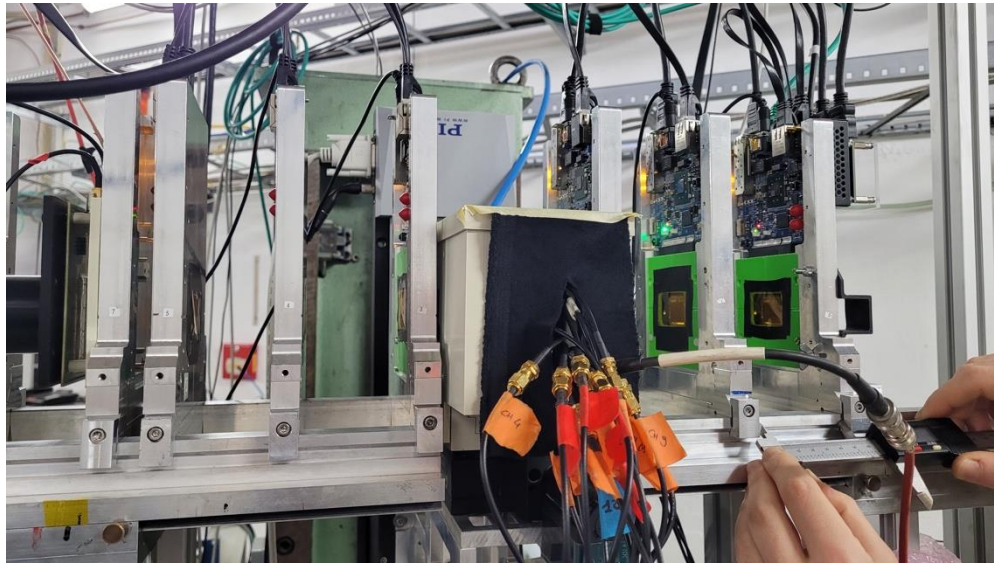
Read 2 pixels using an 8-ch oscilloscope

- Up to 7 electrodes + MCP (time reference)
- High time resolution



The DESY test beam set-up

in pictures....

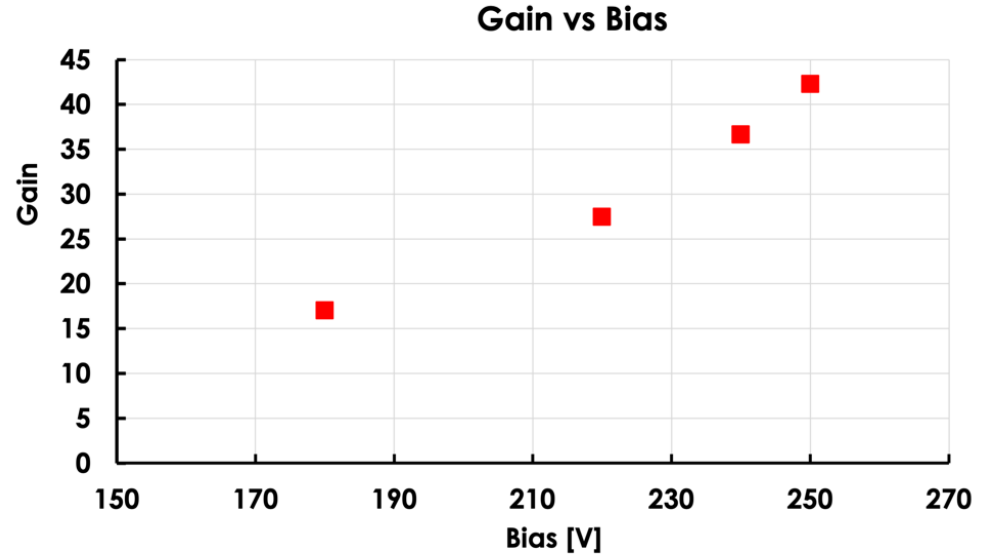


DC-RSD1 W3: gain studies

Wafer 3: “high” p-gain dose, highest n+ resistivity (“slower” propagation on the resistive layer)

High-statistics runs taken at different reverse bias voltages.

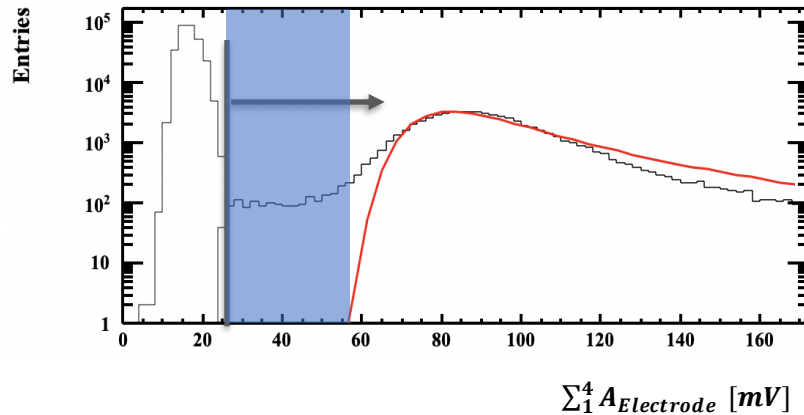
Gain estimated by comparing the signal area measured at a given bias, with the theoretical signal area in a PIN
(uncertainty ~10%)



Gain range used in the analysis: 15 - 45

Signals collected by a pixel

The signal collected by a “pixel” is estimated **summing the amplitudes seen by the four (three) electrodes** defining the squared (triangular) pixel



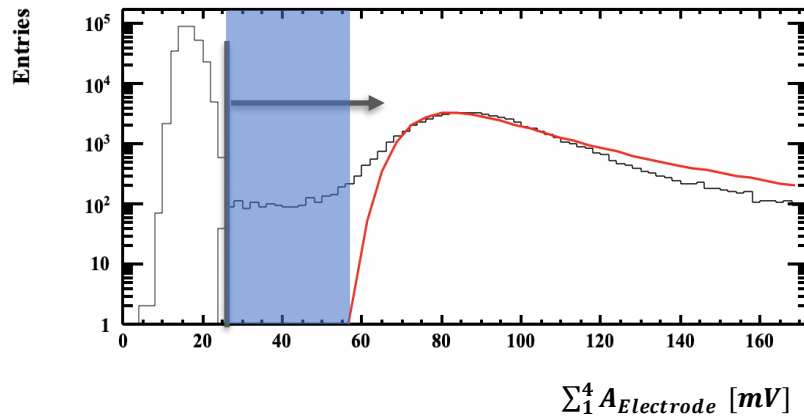
Clear separation between signal (Landau in red) and noise.

Event Selection criteria: $A_{pixel} > 25 \text{ mV}$

Events with **lower amplitudes** are located close to trenches

Signals collected by a pixel: inefficiencies?

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Clear separation between signal (Landau in red) and noise.

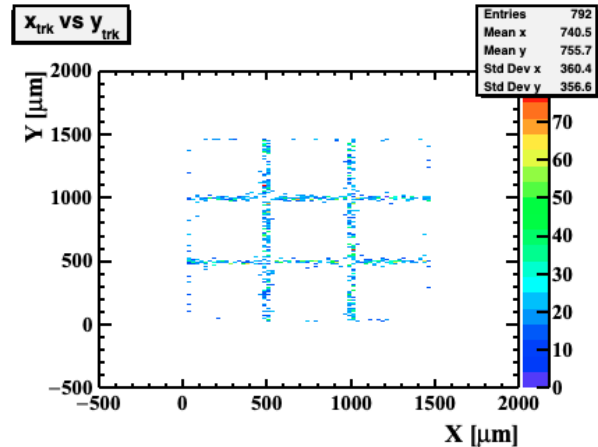
Event Selection criteria: $A_{pixel} > 25 \text{ mV}$

Events with **lower amplitudes** are located close to trenches

Is the DUT inefficient?

Events with tracks inside the active area and

$A_{pixel} < 25 \text{ mV}$

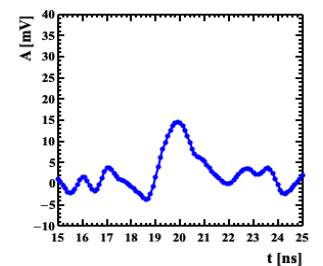
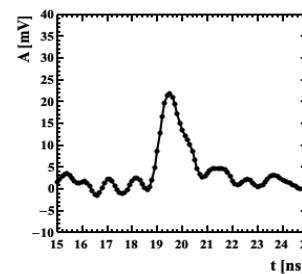
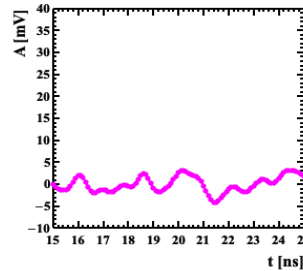
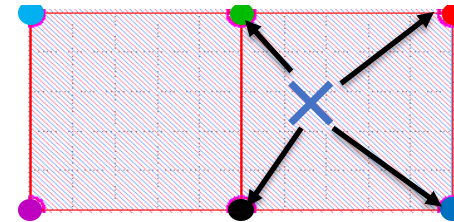
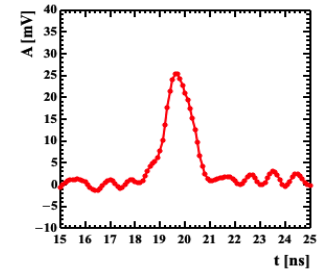
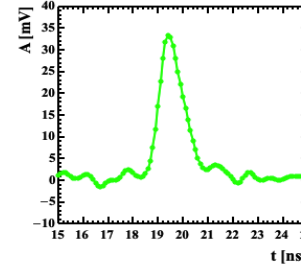
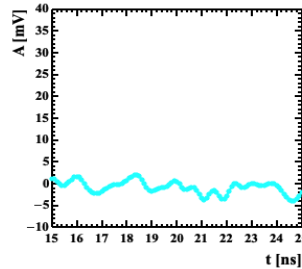


mostly aligned with the trenches!
this is not inefficiency but acceptance
(fill factor ~ 99%)

Signal shape: square pixel, 500-micron pitch

Amplitudes recorded by 6 electrodes (see sketch)

- **The signal is fast**, unipolar, same shape of a standard LGAD.
- **Perfect isolation**: the signal is seen only in the electrodes belonging to the hit pixel.

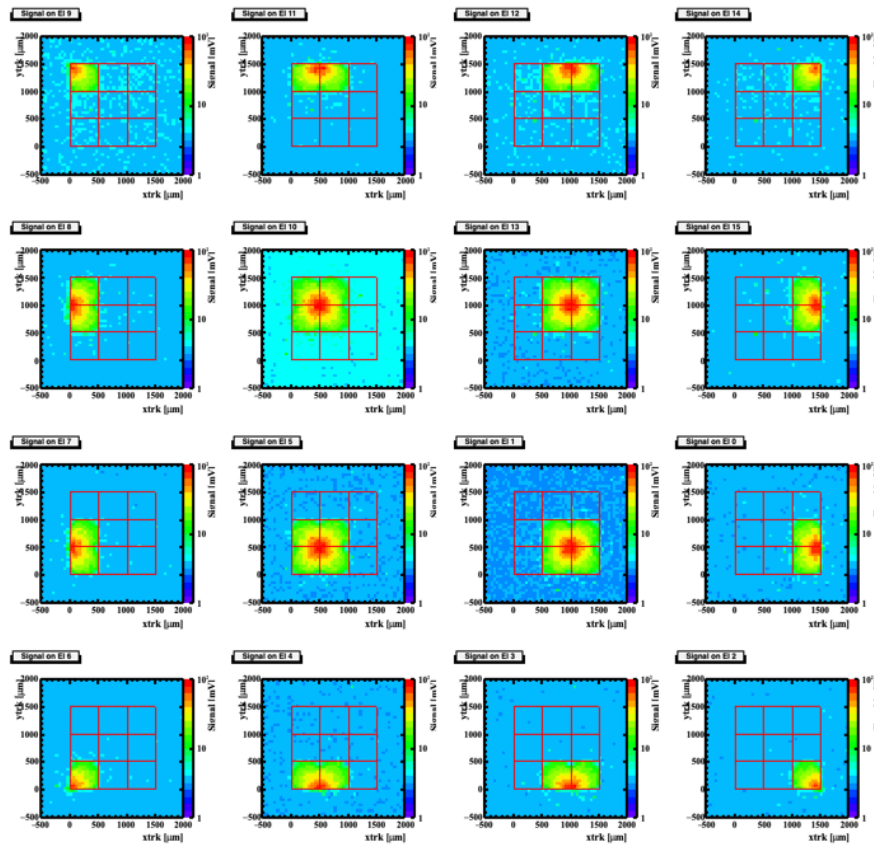
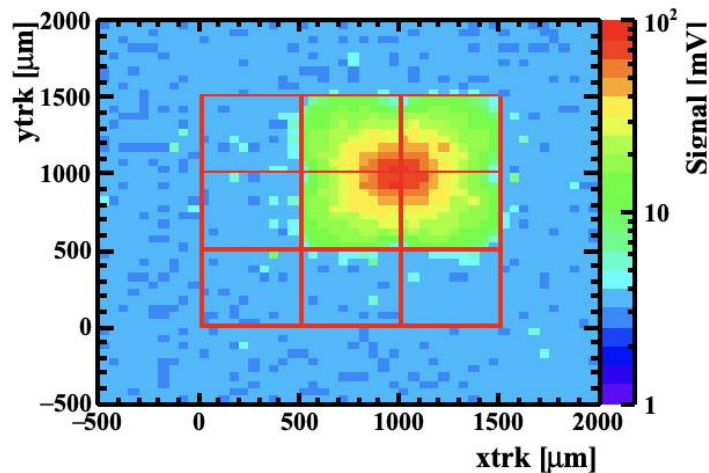


DC-RSD signal containment

Average signal amplitude seen by each electrode as a function of the $(X,Y)_{\text{TRACKER}}$

(Square pixels 230V)

Signal on EI 13



Position reconstruction method: sharing template

Position reconstruction procedure:

- 1) Produce look-up tables with the signal-sharing pattern among the 4 electrodes (done with test beam data).

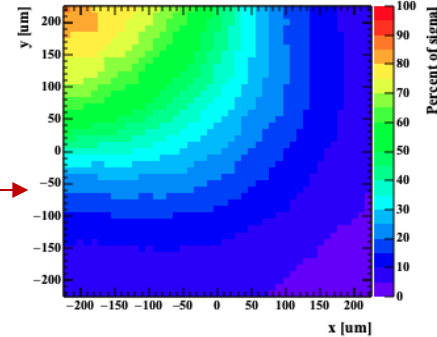
These plots show the signal percentage seen by a given electrode as a function of position (tracker)

- 2) For each event, compare the measured signal sharing with the look-up table to find the location that best reproduces the measured sharing

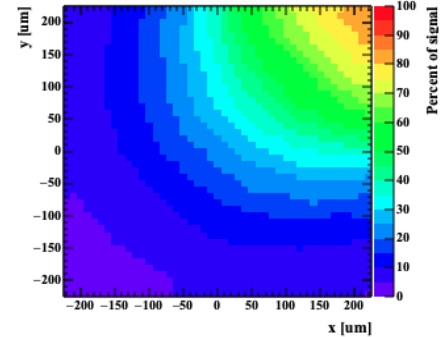
NB:

- DUTs have been **aligned w.r.t. the tracker**
- **Rotations** have been estimated and **corrected for**
- **electrodes amplification** (FNAL board) **inter-calibrated**, equalizing the MPV of the amplitude distributions

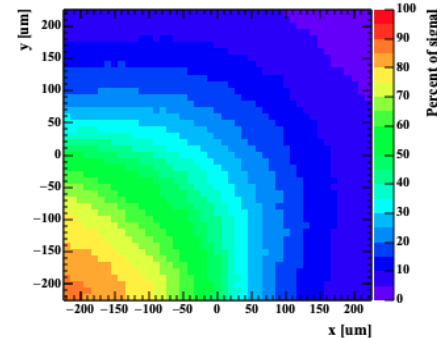
Electrode 0



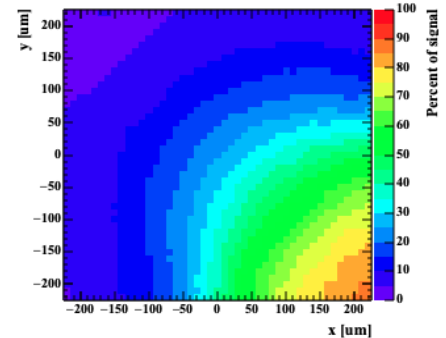
Electrode 1



Electrode 3



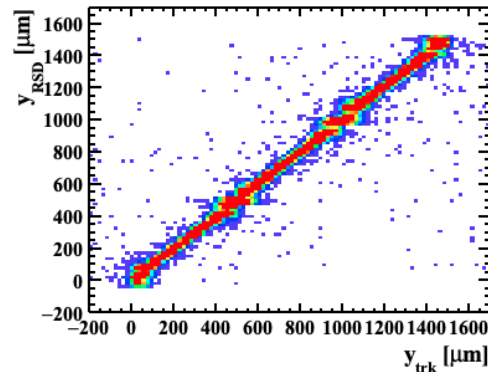
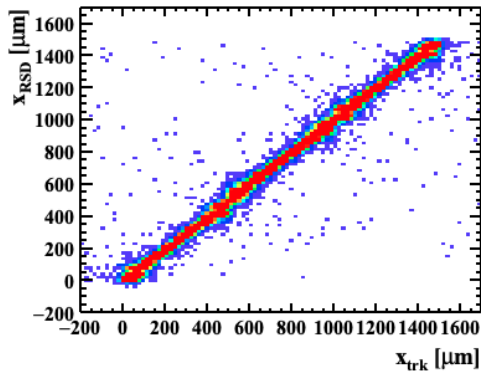
Electrode 2



DC-RSD position resolution

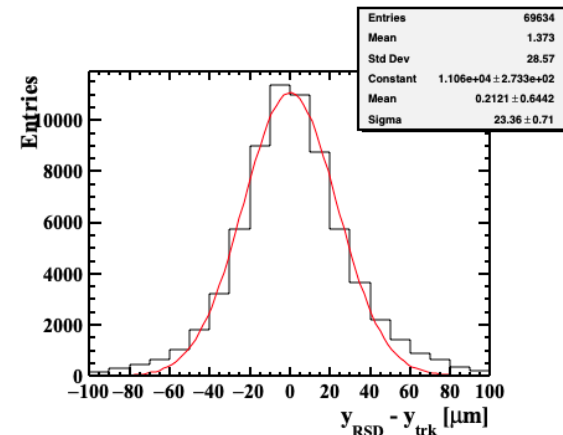
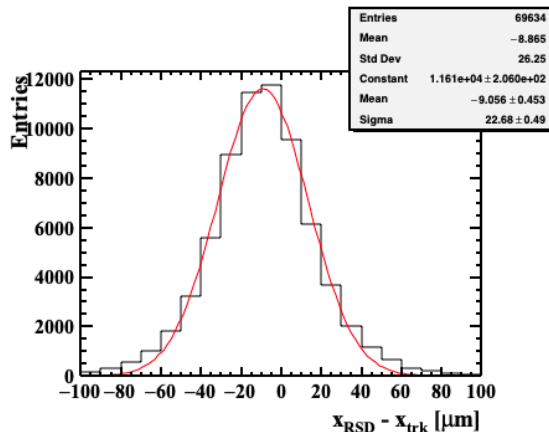
Square matrix, 500-micron
Bias = 240 V (gain ~37)

Correlation between the positions
of tracker and DC-RSD over the
whole 3x3 matrix.



Measurement of the position
resolution $(X, Y)_{\text{DC-RSD}} - (X, Y)_{\text{TRK}}$

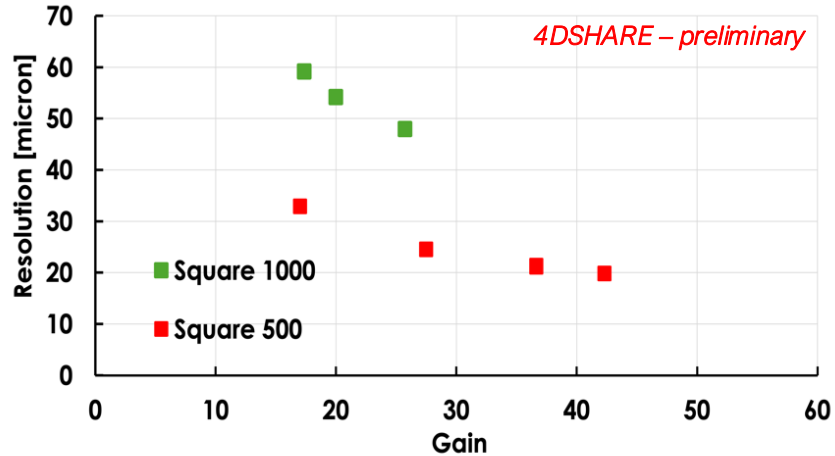
$$\sigma_{x,y} \sim 23 \mu\text{m}$$



Position resolution: summary of results

Resolution for the 500- and 1000-micron pitch squared pixel matrix

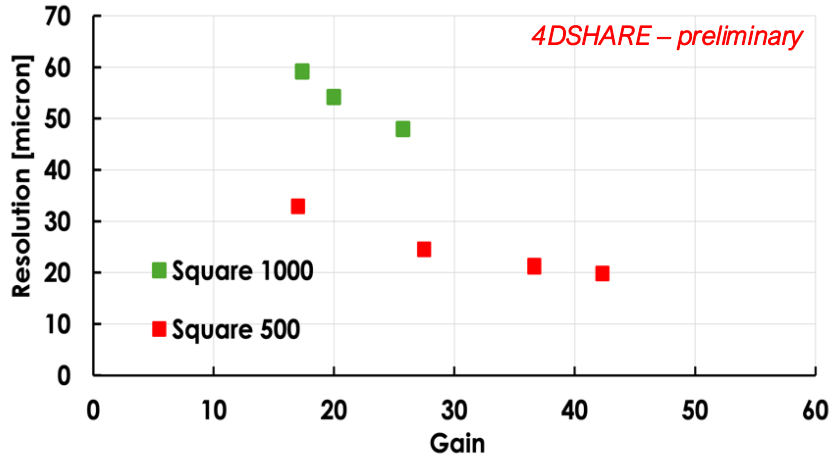
(tracker resolution ~8 micron subtracted)



Position resolution: summary of results

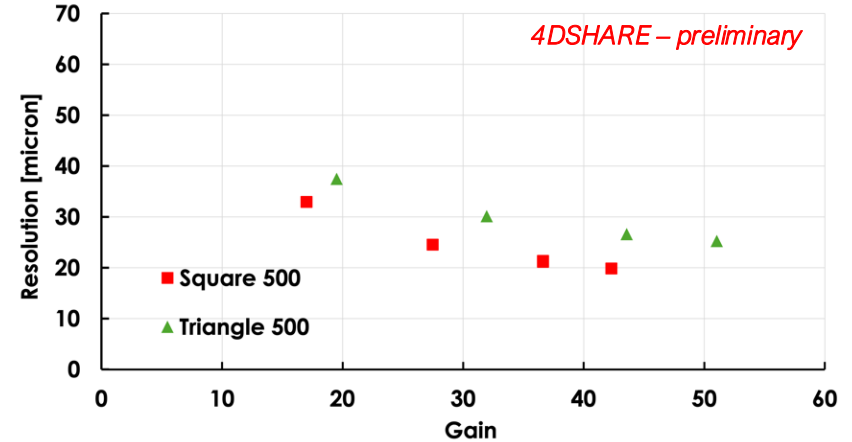
Resolution for the 500- and 1000-micron pitch squared pixel matrix

(tracker resolution ~8 micron subtracted)



Resolution for the 500-micron pitch squared and triangular pixel matrix

(tracker resolution ~8 micron subtracted)



Both sensors reach very good position resolution, below 5% of their pitch

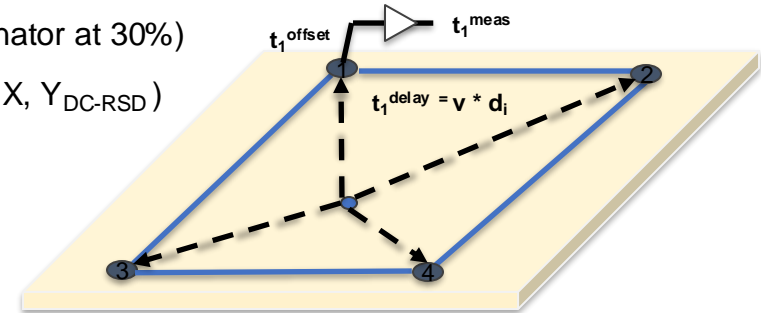
Square pixels are better performing than triangular pixels

Time reconstruction procedure

For each electrode, estimate the time of the hit t_i^{hit}

- Measure the time of arrival t_i^{meas} (constant fraction discriminator at 30%)
- Correct for signal delay $t_i^{delay} = v * d_i$ (d computed using X, Y_{DC-RSD})
- Correct for set-up offset t_i^{offset}

$$t_i^{hit} = t_i^{meas} + t_i^{delay} + t_i^{offset}$$



The delays are calculated assuming a given signal propagation velocity on the n+ layer

The **particle time is computed combining the 4 measurements**, weighted with the squared amplitude

$$t^{hit} = \frac{\sum_1^4 t_i^{hit} A_i^2}{\sum_1^4 A_i^2}$$

Time reconstruction procedure

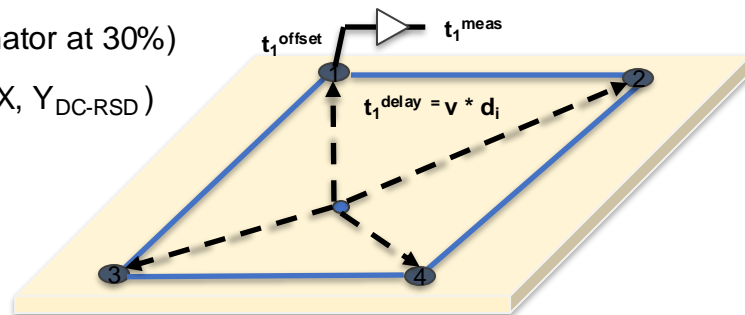
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- Correct for set-up offset t_i^{offset}

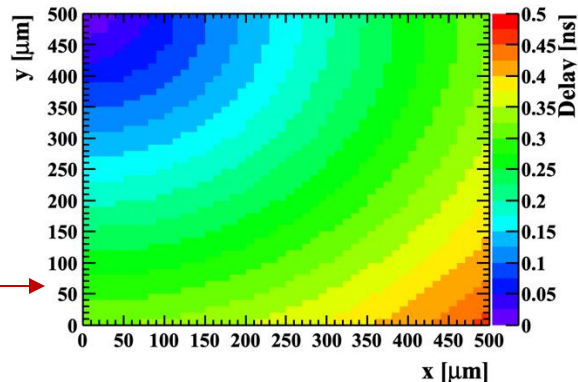
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$$t^{hit} = \frac{\sum_1^4 t_i^{hit} A_i^2}{\sum_1^4 A_i^2}$$



The delays are calculated assuming a given signal propagation velocity on the n+ layer, **which can also be measured using the data**



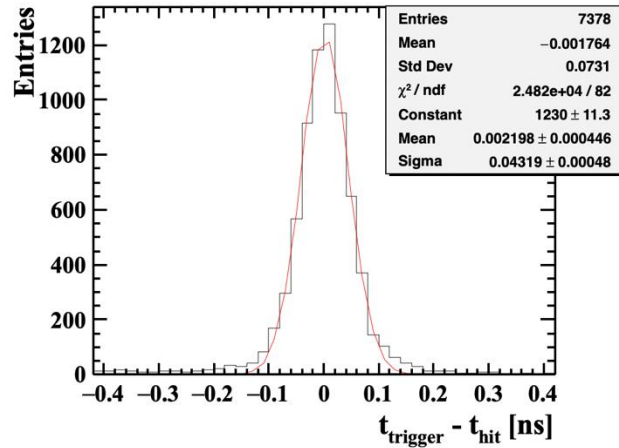
signal delay as a function of the hit position

DC-RSD Time resolution

$$t^{hit} = \frac{\sum_1^4 t_i^{hit} A_i^2}{\sum_1^4 A_i^2}$$

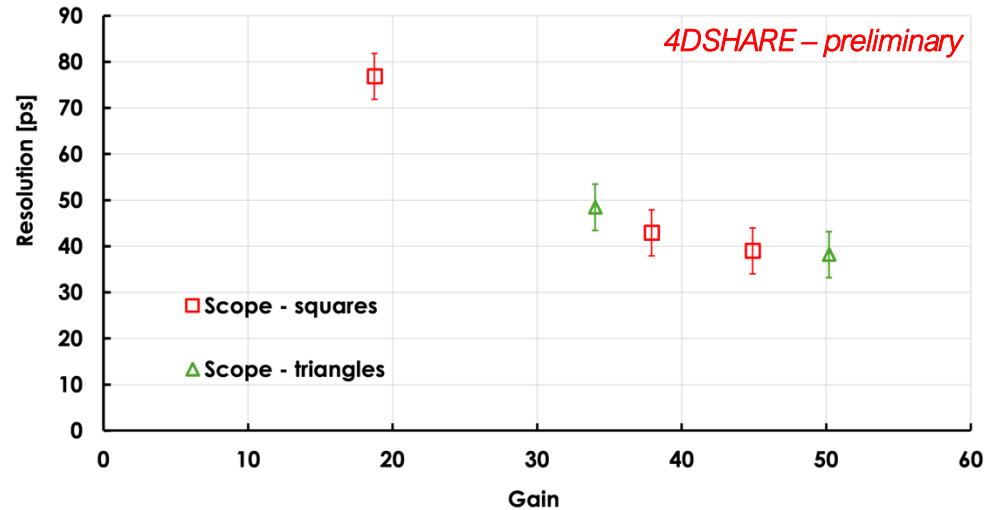
Distribution of $t^{MCP} - t^{hit}$ for 500-micron square matrix,
bias = 240 V

$\sigma_t \sim 43 \text{ ps}$



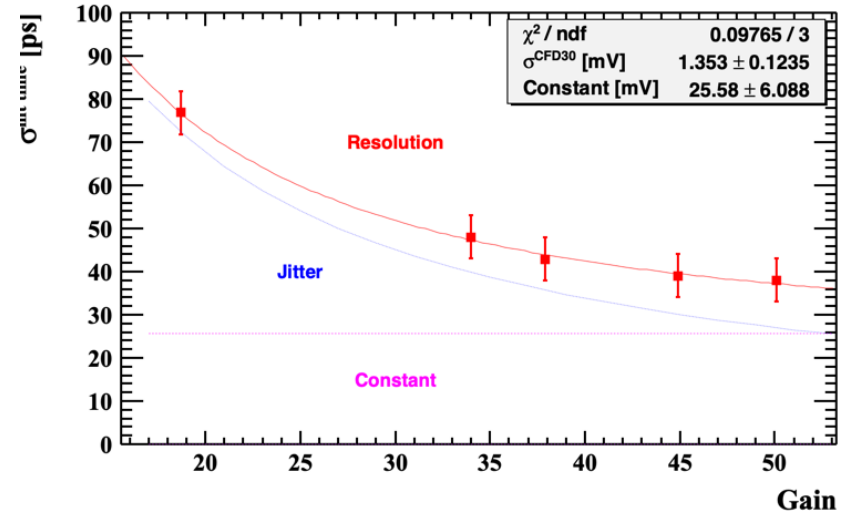
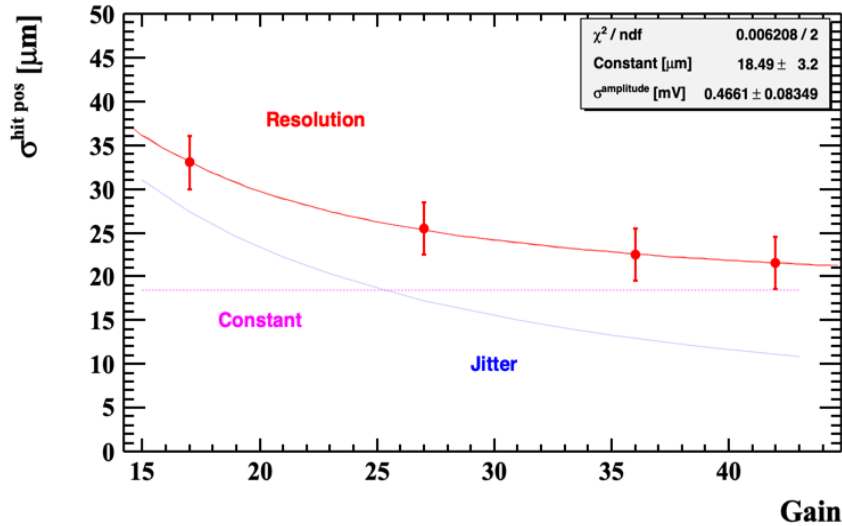
Time resolution for the 500-micron pitch squared and triangular pixel matrix

(time resolution MCP estimated to be 5 ps – subtracted)



Performance DC-RSD “squares” pitch 500

20 micron – 40 ps



Summary and Outlook

The **first prototype run of DC-RSD has been completed** and works very well!

Initial measurements done @FBK on-wafer gave us very important feedback on the success (or problematic points) of the process flow

The main goal of the production, **the realization of matrices of trench-isolated DC-RSD**, has been achieved, with fast and unipolar signals (similar to standard LGADs)

DC-coupled electrodes are alive, the charge is contained by the trenches



Summary and Outlook

The **first prototype run of DC-RSD has been completed** and works very well!

Preliminary measurements of space and time resolution are excellent!

All devices tested (“square” pixels with 500-, 1000-micron pitch and “triangle” pixels with 500-micron side) achieve a **position resolutions better than 5% of the pitch.**

For the square matrix:

- 500-micron pitch: $\sigma_{x,y} \sim 20 \mu\text{m}$
- 1000-micron pitch: $\sigma_{x,y} \sim 48 \mu\text{m}$

Time resolution is $\sigma_t \sim 40 \text{ ps}$ for gains > 40

We are preparing for the second **DC-RSD Test Beam** at **DESY**, adding **DUTs with different pitch size and resistivity.**

Full systematic studies of the production in lab with TCT, beta-source setup are ongoing.



Acknowledgements

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- PRIN MIUR project 2022KLK4LB '4DSHARE': European Union-Next Generation EU, CUP **C53D23001510006**
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- European Union's Horizon Europe research and innovation program under grant agreement no. 101057511 (EuroLABs)

We acknowledge the fruitful discussions with the RD50 and DRD3 collaborations, CERN.

In particular, measurements leading to these results have been performed at the testbeam facility at DESY Hamburg (Germany), a member of the Helmholtz Association (HGF).



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e della Ricerca



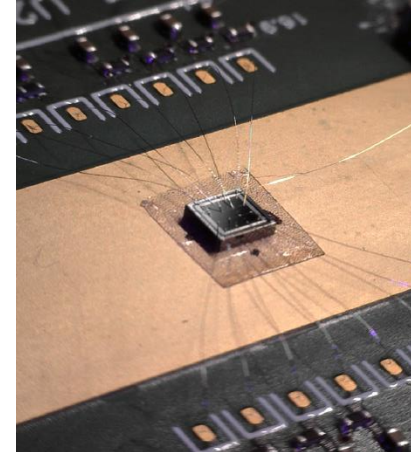
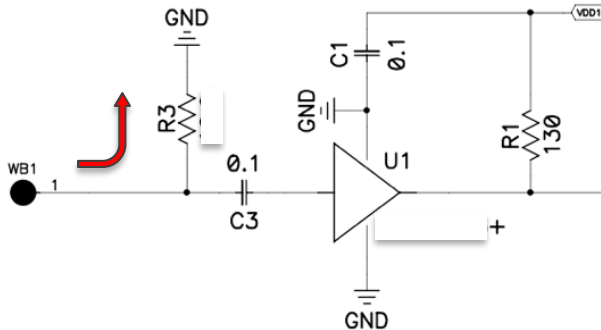
Italiadomani
PIANO NAZIONALE
DI RIPRESA E RESILIENZA

Thanks for the attention!

Back-up material

Front-end board

- 16-ch fast TIA pre-amplifier analog board, developed at FNAL (2-stage amplifier chains based on the Mini-Circuits GALI-66+)
- ~25 ps jitter, fixed gain = 70
- About 1 GHz BW
- Noise ~ 1.5 mV
- Well-suited for DC-RSD read-out (RC input circuit)



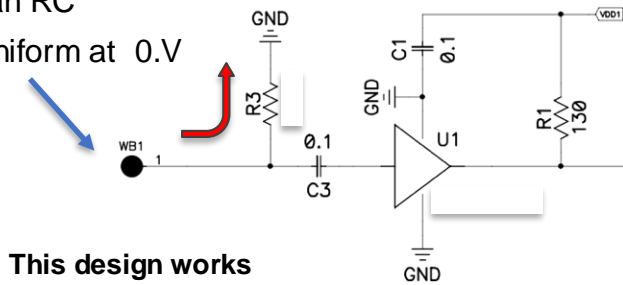
DC-RSD
wirebonded to
FNAL board

DC – RSD front-end amplifiers

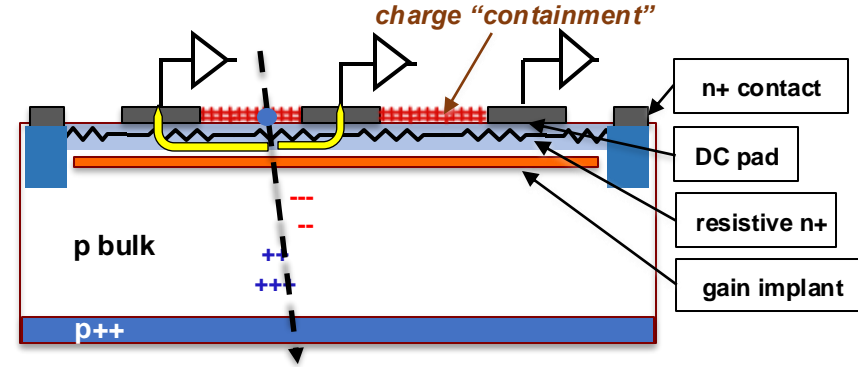
The amplifiers are connected to the same n+ sheet.

For the read-out to work, the amplifiers should polarize the sensor to the same reference level.

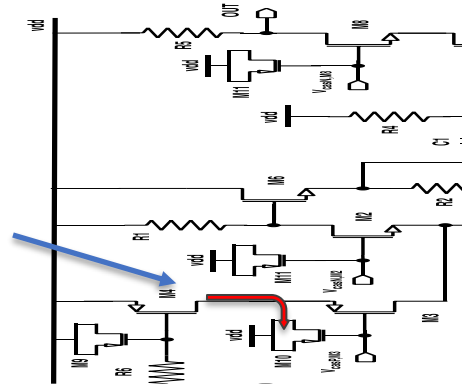
Input into an RC
DC level uniform at 0.V



This design works



Input into a transistor,
DC level non uniform,
about 0.7 V



This design does not work

Data correction: rotations

The DUT can have a rotation in the x-y plane
 Such a rotation will “deform” **the DC-RSD pixel size seen by the tracker**

For a pixel:

RSD dimension: pitch

Tracker dimension: $\text{pitch} \cdot \cos(\vartheta)$

Rotations measured on the 500-microns:

x- rotation: 15 – 20 degrees

y rotation: 0 degrees

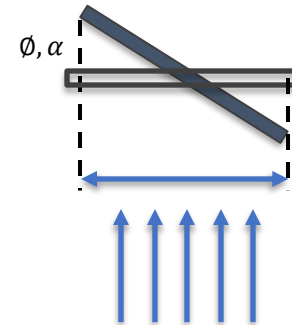
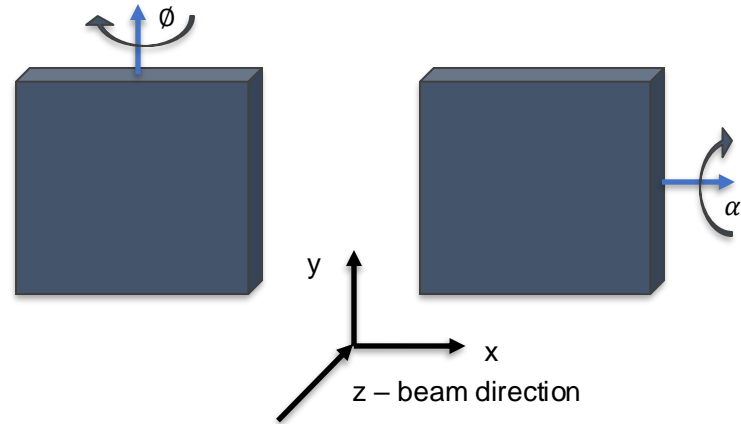
Rotations measured on the 1000-microns:

x- rotation: 15 – 20 degrees

y rotation: 5 - 10 degrees

With a rotation, the RSD coordinates are larger than the tracker's

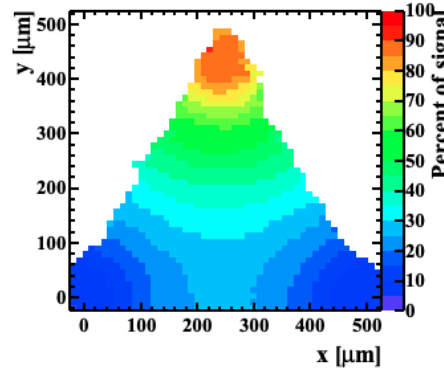
Tracker range:
 $\text{pitch} \cdot \cos(\vartheta)$



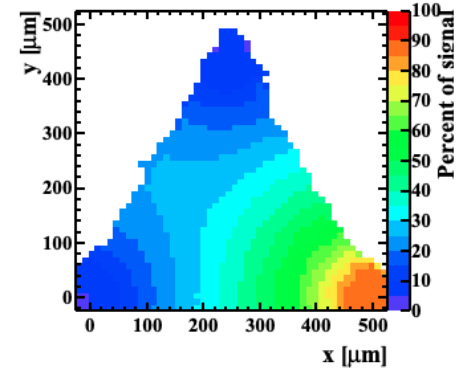
Sharing Template for triangular pixels

Sharing templates for the triangular pixel (500-microns pitch)

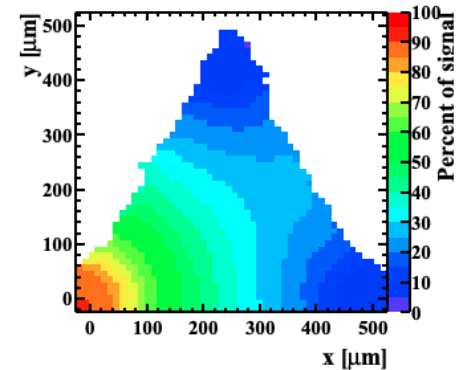
Electrode 0



Electrode 1



Electrode 2

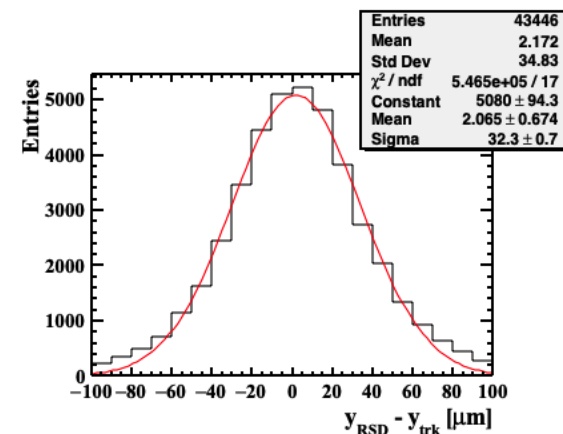
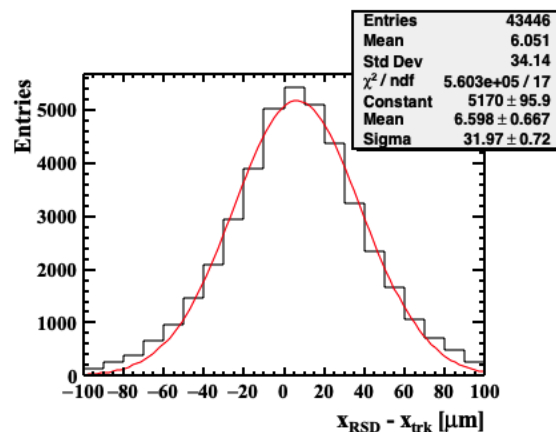
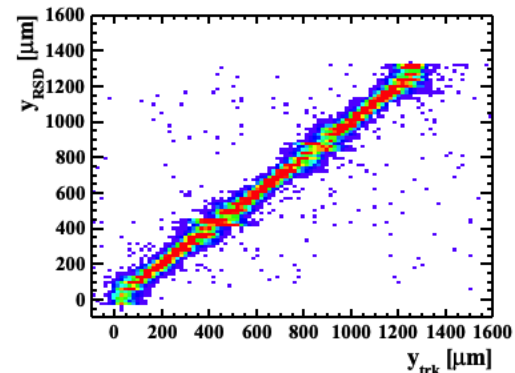
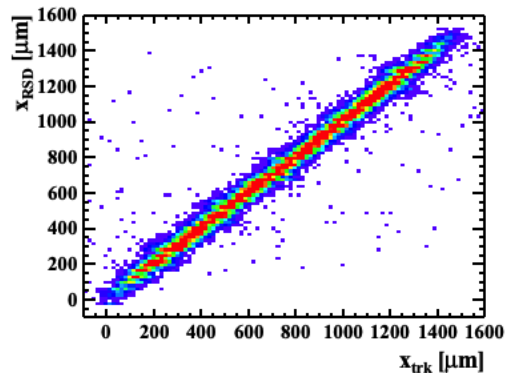


Tracker – DC-RSD position correlation

Triangular matrix, 500-micron
Bias = 240V

- Triangular pixels have a worse resolution with respect of squared pixels
- Sharing among 3 electrodes instead of 4 gives less handles to estimate the positions.

$$\sigma_{x,y} \sim 32 \mu\text{m}$$



DC- RSD setup: DESY tracker resolution

Resolution estimated with the [tracker resolution simulation tool](#) developed for the *Mimosa* telescope in T22.

Changed the description of the telescope planes:

- set the expected resolution of the telescope at the energy we were using (5 GeV) for a configuration without DUT, with planes closest to our setup: 6.5 μm .
- set the ALPIDE planes material budget with 70 μm thick silicon and 25 μm thick Kapton on each side
- set the DUT description with 1 mm PCB, 500 μm thick silicon at Z=222.5 mm

By varying the total material budget of the DUT by $\pm 50\%$ and scanning over the Z position by ± 2.5 mm, obtained

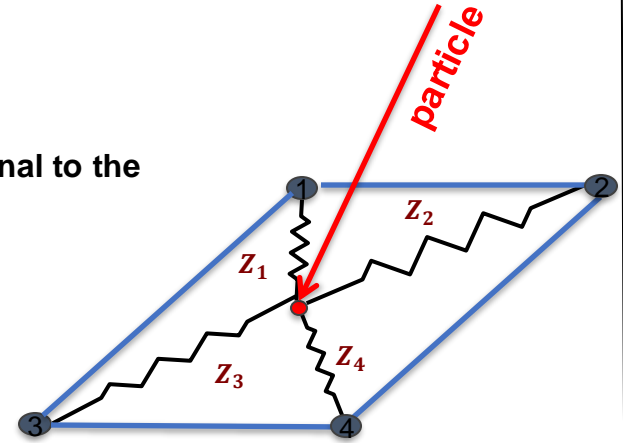
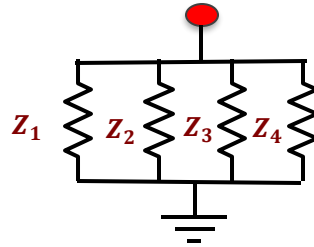
$$\sigma_{trk} = (7.85 \pm 0.5)\mu\text{m}$$

Modeling the spatial resolution

What is currently limiting the spatial resolution that we measure in DC-RSD (and RSDs) ?

Simple analytical model (fit better the DC-RSD design). Assumptions:

- 1) The **impedance** between the hit position and each electrode is **proportional to the distance** $Z_i \propto d_i$
- 2) The signal is **shared as in a perfect resistive divider**



With this model, given a $(X, Y)_{\text{TRUE}}$ we can compute the ideal amplitude sharing among the electrodes, add random noise to each amplitude, compute the sharing fractions.

In a second step, the “noisy sharing fractions” are given to Minuit to find the position $(X, Y)_{\text{RSD}}$ that best fit these inputs. The spatial resolution sigma $[(X, Y)_{\text{TRUE}} - (X, Y)_{\text{RSD}}]$ is computed

Modeling the spatial resolution

What is currently limiting the spatial resolution that we measure in DC-RSD (and RSDs) ?

The model has one free parameter, the noise of the amplitude reconstruction

Noise value is determined fitting the data in a given point. Noise on Amplitude = 1.7 mV

The model has one scale: the pitch.

The model fits the data pleasingly well!

The resolution depends on 3 parameters:

- The signal amplitude
- Noise
- Pitch

